

## Product Preview

### WaveFET™

## Power Surface Mount Products HDTMOS Single N-Channel Field Effect Transistor



**MTD3302**

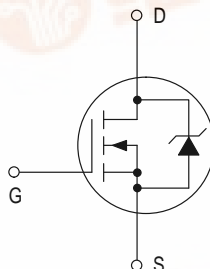
**SINGLE TMOS  
POWER MOSFET  
30 VOLTS  
RDS(on) = 10 mΩ**



**CASE 369A-13, Style 2  
DPAK**

WaveFET™ devices are an advanced series of power MOSFETs which utilize Motorola's latest MOSFET technology process to achieve the lowest possible on-resistance per silicon area. They are capable of withstanding high energy in the avalanche and commutation modes and the drain-to-source diode has a very low reverse recovery time. WaveFET™ devices are designed for use in low voltage, high speed switching applications where power efficiency is important. Typical applications are dc-dc converters, and power management in portable and battery powered products such as computers, printers, cellular and cordless phones. They can also be used for low voltage motor controls in mass storage products such as disk drives and tape drives. The avalanche energy is specified to eliminate the guesswork in designs where inductive loads are switched and offer additional safety margin against unexpected voltage transients.

- Characterized Over a Wide Range of Power Ratings
- Ultralow RDS(on) Provides Higher Efficiency and Extends Battery Life in Portable Applications
- Logic Level Gate Drive — Can Be Driven by Logic ICs
- Diode Is Characterized for Use In Bridge Circuits
- Diode Exhibits High Speed, With Soft Recovery
- IDSS Specified at Elevated Temperature
- Avalanche Energy Specified
- Industry Standard DPAK Surface Mount Package



**WaveFET™**

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	30	Vdc
Drain-to-Gate Voltage	V <sub>DGR</sub>	30	Vdc
Gate-to-Source Voltage	V <sub>GS</sub>	±20	Vdc
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Single Pulse Drain-to-Source Avalanche Energy — Starting T <sub>J</sub> = 25°C (V <sub>DD</sub> = 25 Vdc, V <sub>GS</sub> = 10 Vdc, L = 126 mH, I <sub>L(pk)</sub> = 3.0 A, V <sub>DS</sub> = 30 Vdc)	E <sub>AS</sub>	500	mJ

### DEVICE MARKING

Device	Reel Size	Tape Width	Quantity
D3302 MTD3302T4	13"	12 mm embossed tape	2500

### ORDERING INFORMATION

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## MTD3302

### POWER RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter		Symbol	Value	Unit
Drain Current — Continuous @ $T_A = 25^\circ\text{C}$ — Continuous @ $T_A = 100^\circ\text{C}$ — Single Pulse ( $t_p \leq 10 \mu\text{s}$ ) Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Linear Derating Factor Thermal Resistance — Junction-to-Case	Mounted on heat sink $T_{\text{case}} = 25^\circ\text{C}$  $V_{GS} = 10 \text{ Vdc}$  Steady State	$I_D$	30	Adc
		$I_D$	30	Adc
		$I_{DM}$	70	Adc
		$P_D$	96	Watts
			769	mW/ $^\circ\text{C}$
		$R_{\theta JC}$	1.3	$^\circ\text{C/W}$
Continuous Source Current (Diode Conduction)		$I_S$	2.0	Adc

Parameter		Symbol	Value	Unit
Drain Current — Continuous @ $T_A = 25^\circ\text{C}$ — Continuous @ $T_A = 100^\circ\text{C}$ — Single Pulse ( $t_p \leq 10 \mu\text{s}$ ) Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Linear Derating Factor Thermal Resistance — Junction-to-Ambient	Mounted on 1 inch square FR-4 or G10 board  $V_{GS} = 10 \text{ Vdc}$  Steady State	$I_D$	10.8	Adc
		$I_D$	6.6	Adc
		$I_{DM}$	70	Adc
		$P_D$	1.8	Watts
			14	mW/ $^\circ\text{C}$
		$R_{\theta JA}$	71.4	$^\circ\text{C/W}$
Continuous Source Current (Diode Conduction)		$I_S$	2.0	Adc

Parameter		Symbol	Value	Unit
Drain Current — Continuous @ $T_A = 25^\circ\text{C}$ — Continuous @ $T_A = 100^\circ\text{C}$ — Single Pulse ( $t_p \leq 10 \mu\text{s}$ ) Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Linear Derating Factor Thermal Resistance — Junction-to-Ambient	Mounted on minimum recommended FR-4 or G10 board  $V_{GS} = 10 \text{ Vdc}$  Steady State	$I_D$	8.3	Adc
		$I_D$	5.2	Adc
		$I_{DM}$	60	Adc
		$P_D$	1.0	Watts
			8.3	mW/ $^\circ\text{C}$
		$R_{\theta JA}$	120	$^\circ\text{C/W}$
Continuous Source Current (Diode Conduction)		$I_S$	2.0	Adc

**ELECTRICAL CHARACTERISTICS** ( $T_J = 25^\circ\text{C}$  unless otherwise specified)

Characteristic	Symbol	Min	Typ	Max	Unit
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**OFF CHARACTERISTICS**

Drain-to-Source Breakdown Voltage ( $V_{GS} = 0\text{ Vdc}$ , $I_D = 250\text{ }\mu\text{Adc}$ ) Temperature Coefficient (Positive)	$V_{(BR)DSS}$	30 —	33 23	— —	Vdc mV/ $^\circ\text{C}$
Zero Gate Voltage Drain Current ( $V_{DS} = 30\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ ) ( $V_{DS} = 30\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ , $T_J = 125^\circ\text{C}$ )	$I_{DSS}$	— —	0.02 0.5	1.0 10	$\mu\text{Adc}$
Gate-Body Leakage Current ( $V_{GS} = \pm 20\text{ Vdc}$ , $V_{DS} = 0\text{ Vdc}$ )	$I_{GSS}$	—	—	$\pm 100$	nAdc

**ON CHARACTERISTICS(1)**

Gate Threshold Voltage ( $V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{Adc}$ ) Threshold Temperature Coefficient (Negative)	$V_{GS(th)}$	1.0 —	1.9 4.7	— —	Vdc mV/ $^\circ\text{C}$
Static Drain-to-Source On-Resistance ( $V_{GS} = 10\text{ Vdc}$ , $I_D = 10\text{ Adc}$ ) ( $V_{GS} = 4.5\text{ Vdc}$ , $I_D = 5.0\text{ Adc}$ )	$R_{DS(on)}$	— —	8.9 13	10 16	m $\Omega$
Forward Transconductance ( $V_{DS} = 15\text{ Vdc}$ , $I_D = 10\text{ Adc}$ )	$g_{FS}$	5	13	—	Mhos

**DYNAMIC CHARACTERISTICS**

Input Capacitance	( $V_{DS} = 24\text{ Vdc}$ , $V_{GS} = 0\text{ Vdc}$ , $f = 1.0\text{ MHz}$ )	$C_{iss}$	—	1810	—	pF
Output Capacitance		$C_{oss}$	—	165	—	
Transfer Capacitance		$C_{rss}$	—	595	—	

**SWITCHING CHARACTERISTICS(2)**

Turn-On Delay Time	( $V_{DD} = 25\text{ Vdc}$ , $I_D = 1.0\text{ Adc}$ , $V_{GS} = 10\text{ Vdc}$ , $R_G = 6.0\text{ }\Omega$ )	$t_{d(on)}$	—	9	—	ns
Rise Time		$t_r$	—	10	—	
Turn-Off Delay Time		$t_{d(off)}$	—	60	—	
Fall Time		$t_f$	—	43	—	
Turn-On Delay Time	( $V_{DD} = 25\text{ Vdc}$ , $I_D = 1.0\text{ Adc}$ , $V_{GS} = 4.5\text{ Vdc}$ , $R_G = 6.0\text{ }\Omega$ )	$t_{d(on)}$	—	18	—	ns
Rise Time		$t_r$	—	32	—	
Turn-Off Delay Time		$t_{d(off)}$	—	42	—	
Fall Time		$t_f$	—	44	—	
Gate Charge	( $V_{DS} = 15\text{ Vdc}$ , $I_D = 2.0\text{ Adc}$ , $V_{GS} = 10\text{ Vdc}$ )	$Q_T$	—	46	60	nC
		$Q_1$	—	5.3	—	
		$Q_2$	—	10.7	—	
		$Q_3$	—	10.3	—	

**SOURCE-DRAIN DIODE CHARACTERISTICS**

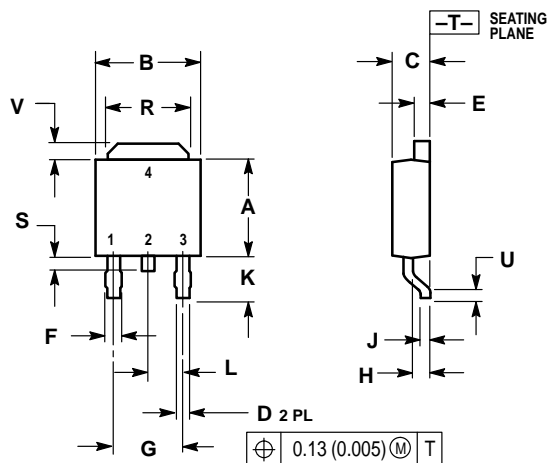
Forward On-Voltage (1)	( $I_S = 2.3\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ ) ( $I_S = 2.3\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ , $T_J = 125^\circ\text{C}$ )	$V_{SD}$	— —	0.75 0.58	1.1 —	Vdc
Reverse Recovery Time	( $I_S = 2.3\text{ Adc}$ , $V_{GS} = 0\text{ Vdc}$ , $di_S/dt = 100\text{ A}/\mu\text{s}$ )	$t_{rr}$	—	36	—	ns
		$t_a$	—	21	—	
		$t_b$	—	15	—	
Reverse Recovery Stored Charge		$Q_{RR}$	—	0.041	—	$\mu\text{C}$

(1) Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2\%$ .

(2) Switching characteristics are independent of operating junction temperatures.

# MTD3302

## PACKAGE DIMENSIONS




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.250	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090 BSC		2.29 BSC	
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020	—	0.51	—
V	0.030	0.050	0.77	1.27
Z	0.138	—	3.51	—

- STYLE 2:
1. GATE
  2. DRAIN
  3. SOURCE
  4. DRAIN

**CASE 369A-13  
ISSUE Y**

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